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Q.1 - 30 Carry One Mark Each

MCQ 1.1 Consider the network graph shown in the figure. Which one of the following is NOT a 'tree' of this graph ?



SOL 1.1 For a tree there must not be any loop. So a, c, and d don't have any loop. Only b has loop.

Hence (B) is correct option.

MCQ 1.2 The equivalent inductance measured between the terminals 1 and 2 for the circuit shown in the figure is



SOL 1.2 The sign of M is as per sign of L If current enters or exit the dotted terminals of both coil. The sign of M is opposite of L If current enters in dotted terminal of a coil and exit from the dotted terminal of other coil.

Thus $L_{eq} = L_1 + L_2 - 2M$ Hence (D) is correct option.

MCQ 1.3 The circuit shown in the figure, with $R = \frac{1}{3}\Omega$, $L = \frac{1}{4}H$ and C = 3F has input voltage $v(t) = \sin 2t$. The resulting current i(t) is



MCQ 1.4 For the circuit shown in the figure, the time constant RC = 1 ms. The input voltage is $v_i(t) = \sqrt{2} \sin 10^3 t$. The output voltage $v_o(t)$ is equal to



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	Impedance	$Z(s) = s + 2$ $I(s) = \frac{V_i(s)}{V_i(s)} = -$	1
		$r(3) = \frac{1}{s+2} = \frac{1}{s}$	(s+2)
	or	$I(s) = \frac{1}{2} \left[\frac{1}{s} - \frac{1}{s+1} \right]$	2
	Taking inverse laplace	transform	
		$i(t) = \frac{1}{2}(1 - e^{-2t})$) u(t)
	At $t = 0$, $i(t) = 0$ At $t = \frac{1}{2}$, $i(t) = 0.31$ At $t = \infty$, $i(t) = 0.5$ Graph (C) satisfies all	these conditions.	
MCQ 1.6	The impurity common	ily used for realizing	ing the base region of a silicon $n - p - n$
	transistor is		(B) Indium
	(C) Boron		(D) Phosphorus
SOL 1.6	Trivalent impurities ar	e used for making	<i>p</i> type semiconductor. Boron is trivalent.
	Hence option (C) is co	rrect a t e	
MCQ 1.7	If for a silicon npn tra collector-to-base voltag (A) normal active mod	C_{CB} is 0.2 V, the base- ge (V_{CB}) is 0.2 V, the second	to-emitter voltage (V_{BE}) is 0.7 V and the then the transistor is operating in the (B) saturation mode
	(C) inverse active mod	.e	(D) cutoff mode
SOL 1.7	Here emitter base junctions biased. Thus transiston Hence option (A) is co	tion is forward bia a is operating in neuropert.	sed and base collector junction is reversed ormal active region.
MCQ 1.8	Consider the following	statements S1 and	d S2.
	S1 : The β of a bipolar	r transistor reduce	s if the base width is increased.
	S2 : The β of a bipolar is increased.	transistor increas	es if the dopoing concentration in the base
	Which remarks of the (A) S1 is FALSE and S	following is correc S2 is TRUE	t ?
	(B) Both S1 and S2 ar	e TRUE	
	(C) Both S1 and S2 ar	e FALSE	
	(D) S1 is TRUE and S	2 is FALSE	
SOL 1.8	Hence option (D) is co	rrect.	
	We have $\beta = \frac{\alpha}{1 - \alpha}$		

	Thus $\alpha \uparrow \rightarrow \beta \uparrow$ $\alpha \downarrow \rightarrow \beta \downarrow$ If the base width increases, recombination of carrier in base region increases and α decreases & hence β decreases. If doping in base region increases, recombination of carrier in base increases and α decreases thereby decreasing β . Thus S_1 is true and S_2 is false.
MCQ 1.9	An ideal op-amp is an ideal(A) voltage controlled current source(B) voltage controlled voltage source(C) current controlled current source(D) current controlled voltage source
SOL 1.9	An ideal OPAMP is an ideal voltage controlled voltage source. Hence (B) is correct option.
MCQ 1.10	 Voltage series feedback (also called series-shunt feedback) results in (A) increase in both input and output impedances (B) decrease in both input and output impedances (C) increase in input impedance and decrease in output impedance (D) decrease in input impedance and increase in output impedance
SOL 1.10	In voltage series feed back amplifier, input impedance increases by factor $(1 + A\beta)$ and output impedance decreases by the factor $(1 + A\beta)$. $R_{if} = R_i(1 + A\beta)$ $R_{of} = \frac{R_o}{(1 + A\beta)}$ Hence (C) is correct option.
MCQ 1.11	The circuit in the figure is a

- (A) low-pass filter
- (C) band-pass filter

SOL 1.11This is a Low pass filter, becauseAt $\omega = \infty$ $\frac{V_0}{V_{in}} = 0$ and at $\omega = 0$ $\frac{V_0}{V_{in}} = 1$

Hence (A) is correct option.

- (B) high-pass filter
- (D) band-reject filter

MCQ 1.12 Assuming $V_{CEsat} = 0.2$ V and $\beta = 50$, the minimum base current (I_B) required to drive the transistor in the figure to saturation is



- **VCQ 1.14** The range of signed decimal numbers that can be represented by 6-bits 1's complement number is
 - (A) -31 to +31(B) -63 to +63(C) -64 to +63(D) -32 to +31

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SOL 1.14	The range of signed decimal numbers the complement number is $-(2^{n-1}-1)$ to $+(2^n)$. Thus for $n = 6$ we have Range $= -(2^{6-1}-1)$ to $+(2^{6-1}-1)$ = -31 to $+31Hence (A) is correct answer.$	hat can be represented by $n - $ bits 1's $n^{n-1} - 1$).
MCQ 1.15	A digital system is required to amplify a should be able to control the gain of the a in 100 increments. The minimum number binary, is (A) 8 (I (C) 5 (I	binary-encoded audio signal. The user amplifier from minimum to a maximum of bits required to encode, in straight B) 6 D) 7
SOL 1.15	The minimum number of bit require to end $2^n \ge 100$ or $n \ge 7$ Hence (D) is correct answer.	code 100 increment is
MCQ 1.16	Choose the correct one from among the aitem from Group 1 most appropriate itemGroup 1Group 2P. Shift register1. FrequeQ. Counter2. AddreR. Decoder3. Serial(A) $P-3, Q-2, R-1$ (1)(C) $P-2, Q-1, R-3$ (1)	lternatives A, B, C, D after matching an in Group 2. ency division essing in memory chips to parallel data conversion B) $P-3, Q-1, R-2$ D) $P-1, Q-2, R-2$
SOL 1.16	Shift Register \rightarrow Serial to parallel data con Counter \rightarrow Frequency division Decoder \rightarrow Addressing in memory chips. Hence (B) is correct answer.	nversion
MCQ 1.17	The figure the internal schematic of a TT the inputs shown in the figure, the output $A = A = A = A = A = A = A = A = A = A $	L AND-OR-OR-Invert (AOI) gate. For Y is
	$ \begin{array}{c} (A) \ 0 \\ (C) \ AB \end{array} \tag{1} $	B) 1 D) \overline{AB}
SOL 1.17	For the TTL family if terminal is floating, Thus $Y = (\overline{AB+1}) = \overline{AB}.0 = 0$	then it is at logic 1.

Hence (A) is correct answer.





- (A) an NOMS inverter with enhancement mode transistor as load
- (B) an NMOS inverter with depletion mode transistor as load
- (C) a CMOS inverter
- (D) a BJT inverter

SOL 1.18 Hence option (C) is correct

- **MCQ 1.19** The impulse response h[n] of a linear time-invariant system is given by h[n] = u[n+3] + u[n-2) 2n[n-7] where u[n] is the unit step sequence. The above system is
 - (A) stable but not causal **[] []** (B) stable and causal
 - (C) causal but unstable (D) unstable and not causal
- **SOL 1.19** A system is stable if $\sum_{n=-\infty}^{\infty} |h(n)| < \infty$. The plot of given h(n) is



Hence system is stable but $h(n) \neq 0$ for n < 0. Thus it is not causal. Hence (A) is correct answer.

MCQ 1.20 The distribution function $F_x(x)$ of a random variable x is shown in the figure. The probability that X = 1 is



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 $\angle G(j\omega) H(j\omega) = -180^{\circ} + \tan^{-1}\omega$ The frequency at which phase becomes -180° , is called phase crossover frequency. $-180 = -180^{\circ} + \tan^{-1}\omega_{\phi}$ Thus $\tan^{-1}\omega_{\phi}=0$ or $\omega_{\phi} = 0$ or The gain at $\omega_{\phi} = 0$ is $|G(j\omega)H(j\omega)| = \frac{2\sqrt{1+\omega^2}}{2} = \infty$ Thus gain margin is = $\frac{1}{2} = 0$ and in dB this is $-\infty$. Hence (D) is correct option Given $G(s)H(s) = \frac{K}{s(s+1)(s+3)}$. The point of intersection of the asymptotes of the root loci with the real axis is **MCQ 1.24** (A) - 4(B) 1.33 (C) - 1.33(D) 4 Centroid is the point where all asymptotes intersects. SOL 1.24 $\sigma = \frac{\Sigma \text{Real of Open Loop Pole} - \Sigma \text{Real Part of Open Loop Pole}}{\Sigma \text{No.of Open Loop Pole} - \Sigma \text{No.of Open Loop zero}}$ $=\frac{-1-3}{3}$ **g** 1**33 t e** Hence (C) is correct option. In a PCM system, if the code word length is increased from 6 to 8 bits, the signal **MCQ 1.25** to quantization noise ratio improves by the factor (A) $\frac{8}{6}$ (B) 12(C) 16 (D) 8 When word length is 6 **SOL 1.25** $\left(\frac{S}{N}\right)_{N=6} = 2^{2\times 6} = 2^{12}$ When word length is 8 $\left(\frac{S}{N}\right)_{\!\!N=8}=2^{2\times 8}=2^{16}$ Now $\frac{\left(\frac{S}{N}\right)_{N=8}}{\left(\frac{S}{N}\right)_{N=6}} = \frac{2^{16}}{2^{12}} = 2^4 = 16$ Thus it improves by a factor of 16. Hence (C) is correct option. An AM signal is detected using an envelop detector. The carrier frequency and **MCQ 1.26** modulating signal frequency are 1 MHz and 2 kHz respectively. An appropriate value for the time constant of the envelop detector is (A) $500\mu \sec$ (B) $20\mu \sec$ Brought to you by: Nodia and Company Visit us at: www.nodia.co.in

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(C) $0.2\mu \sec$ (D) $1\mu \sec$ SOL 1.26 Hence (B) is correct option. $f_c = 1 \times 10^6 \text{ Hz}$ Carrier frequency Modulating frequency $f_m = 2 \times 10^3 \text{ Hz}$ For an envelope detector $2\pi f_c > \frac{1}{R_c} > 2\pi f_m$ $\frac{1}{2\pi f_c} < RC < \frac{1}{2\pi f_m}$ $\frac{1}{2\pi f_c} < RC < \frac{1}{2\pi f_m}$ $\frac{1}{2\pi 10^6} < RC < \frac{1}{2 \times 10^3}$ $1.59 \times 10^{-7} < RC < 7.96 \times 10^{-5}$ so, 20 µsec sec best lies in this interval. **MCQ 1.27** An AM signal and a narrow-band FM signal with identical carriers, modulating signals and modulation indices of 0.1 are added together. The resultant signal can be closely approximated by **T C** (B) SSB with carrier d (A) broadband FM (D) SSB without carrier (C) DSB-SC Hence (B) is correct option. SOL 1.27 $S_{AM}(t) = A_c [1 + 0.1 \cos \omega_m t] \cos \omega_m t$ $s_{NBFM}(t) = A_c \cos\left[\omega_c t + 0.1\sin\omega_m t\right]$ $s(t) = S_{AM}(t) + S_{NB} f_m(t)$ $= A_c [1 + 0.1 \cos \omega_m t] \cos \omega_c t + A_c \cos (\omega_c t + 0.1 \sin \omega_m t)$ $= A_c \cos \omega_c t + A_c 0.1 \cos \omega_m t \cos \omega_c t$ $+A_c \cos \omega_c t \cos (0.1 \sin \omega_m t) - A_c \sin \omega_c t \sin (0.1 \sin \omega_m t)$ \mathbf{As} $0.1 \sin \omega_m t \cong +0.1$ to -0.1so $\cos\left(0.1\sin\omega_m t\right) \approx 1$ As when θ is small $\cos \theta \approx 1$ and $\sin \theta \simeq \theta$, thus $\sin\left(0.1\sin\omega_m t\right) = 0.1\sin\cos\omega_c t\cos\omega_m t + A_c\cos\omega_c t - A_c 0.1\sin\omega_m t\sin\omega_c t$ $= \underbrace{2A_c \cos \omega_c t}_{\text{cosec}} + \underbrace{0.1A_c \cos \left(\omega_c + \omega_m\right) t}_{USB}$ Thus it is SSB with carrier. In the output of a DM speech encoder, the consecutive pulses are of opposite **MCQ 1.28**

MCQ 1.28 In the output of a DM speech encoder, the consecutive pulses are of opposite polarity during time interval $t_1 \le t \le t_2$. This indicates that during this interval (A) the input to the modulator is essentially constant

(B) the modulator is going through slope overload

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	(C) the accumulator is in saturation(D) the speech signal is being sampled at the Nyquist rate	
SOL 1.28	Consecutive pulses are of same polarity when modulator is in slop Consecutive pulses are of opposite polarity when the input is con- Hence (A) is correct option.	pe overload. stant.
MCQ 1.29	 The phase velocity of an electromagnetic wave propagating in a rectangular waveguide in the TE₁₀ mode is (A) equal to its group velocity (B) less than the velocity of light in free space (C) equal to the velocity of light in free space (D) greater than the velocity of light in free space 	a hollow metallic
SOL 1.29	We know that $v_p > c > v_g$. Hence (D) is correct option.	
MCQ 1.30	Consider a lossless antenna with a directive gain of +6 dB. If 1 m to it the total power radiated by the antenna will be (A) 4 mW (B) 1 mW (C) 7 mW D a 1 B (D) 1/4 mW	W of power is fed
SOL 1.30	Hence (A) is correct option. We have $G_D(\theta, \phi) = \frac{4\pi U(\theta, \phi)}{P_{rad}}$ help For lossless antenna $P_{rad} = P_{in}$ Here we have $P_{rad} = P_{in} = 1 \text{ mW}$ and $10 \log G_D(\theta, \phi) = 6 \text{ dB}$ or $G_D(\theta, \phi) = 3.98$ Thus the total power radiated by antenna is $4\pi U(\theta, \phi) = P_{rad} G_D(\theta, \phi) = 1 \text{ m} \times 3.98 = 3.98 \text{ mW}$	
	Q.31 - 90 Carry Two Marks Each	
MCQ 1.31	For the lattice shown in the figure, $Z_a = j2 \Omega$ and $Z_b = 2 \Omega$. The vertice shown in the figure $\begin{bmatrix} z_{11} & z_{12} \end{bmatrix}$ and	values of the open



Brought to you by: Nodia and Company PUBLISHING FOR GATE (A) $\begin{bmatrix} 1-j & 1+j \\ 1+j & 1+j \end{bmatrix}$ (C) $\begin{bmatrix} 1+j & 1+j \\ 1-j & 1-j \end{bmatrix}$ We know that $z_{12}I_2$ $z_{22}I_2$ where

(B)
$$\begin{bmatrix} 1-j & 1+j \\ -1+j & 1-j \end{bmatrix}$$

(D)
$$\begin{bmatrix} 1+j & -1+j \\ -1+j & 1+j \end{bmatrix}$$

SOL 1.31

$$V_{1} = z_{11}I_{1} + z_{11}$$

$$V_{2} = z_{11}I_{1} + z_{11}$$

$$z_{11} = \frac{V_{1}}{I_{1}}\Big|_{I_{2}=0}$$

$$z_{21} = \frac{V_{2}}{I_{1}}\Big|_{I_{1}=0}$$

Consider the given lattice network, when $I_2 = 0$. There is two similar path in the circuit for the current I_1 . So $I = \frac{1}{2}I_1$



Thus

 $V_2 = \frac{1}{2}I_1(Z_a - Z_b)$ $z_{21} = \frac{1}{2}(Z_a - Z_b)$

For this circuit $z_{11} = z_{22}$ and $z_{12} = z_{21}$. Thus

	$Z_a + Z_b$	$Z_a - Z_b$
z_{11} z_{12}	2	2
$ _{z_{21}} _{z_{22}} =$	$Z_a - Z_b$	$Z_a + Z_b$
	2	2
	L	l
$Z_a = 2j$ and	$Z_b = 2\Omega$	
		1]

Here Thus $\begin{vmatrix} z_{11} & z_{12} \\ z_{21} & z_{22} \end{vmatrix} = \begin{vmatrix} 1+j & j-1 \\ j-1 & 1+j \end{vmatrix}$

Hence (D) is correct option.

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MCQ 1.32 The circuit shown in the figure has initial current $i_L(0^-) = 1$ A through the inductor and an initial voltage $v_C(0^-) = -1$ V across the capacitor. For input v(t) = u(t), the Laplace transform of the current i(t) for $t \ge 0$ is



Hence (B) is correct option.

MCQ 1.33 Consider the Bode magnitude plot shown in the fig. The transfer function H(s) is



SOL 1.32

-20 dB/sec





-20



SOL 1.34 Characteristics equation is $s^2 + 20s + 10^6 = 0$ Comparing with $s^2 + 2\xi\omega_n s + \omega_n^2 = 0$ we have $\omega_n = \sqrt{10^6} = 10^3$ $2\xi\omega = 20$ Thus $2\xi = \frac{20}{10^3} = 0.02$ Now $Q = \frac{1}{2\xi} = \frac{1}{0.02} = 50$ Hence (B) is correct option.

MCQ 1.35 For the circuit shown in the figure, the initial conditions are zero. Its transfer function $H(s) = \frac{V_c(s)}{V_i(s)}$ is



SOL 1.35 Hence (D) is correct option.

$$H(s) = \frac{V_0(s)}{V_i(s)}$$

$$= \frac{\frac{1}{sC}}{R + sL + \frac{1}{sC}} = \frac{1}{s^2LC + sCR + 1}$$

$$= \frac{1}{s^2(10^{-2} \times 10^{-4}) + s(10^{-4} \times 10^4) + 1}$$

$$= \frac{1}{10^{-6}s^2 + s + 1} = \frac{10^6}{s^2 + 10^6s + 10^6}$$

MCQ 1.36 A system described by the following differential equation $\frac{d^2 y}{dt^2} + 3\frac{dy}{dt} + 2y = x(t)$ is initially at rest. For input x(t) = 2u(t), the output y(t) is (A) $(1 - 2e^{-t} + e^{-2t})u(t)$ (B) $(1 + 2e^{-t} - 2e^{-2t})u(t)$ (C) $(0.5 + e^{-t} + 1.5e^{-2t})u(t)$ (D) $(0.5 + 2e^{-t} + 2e^{-2t})u(t)$

SOL 1.36 Hence Correct Option is (A) Given, $\frac{d^2y}{dt^2} + 3\frac{dy}{dt} + 2y = x(t)$

Taking Laplace Transformation both sides, we have

$$[s^{2}+3s+2]Y(s) = X(s) = \frac{2}{s}$$

or

$$Y(s) = \frac{2}{s(s+1)(s+2)} = \frac{1}{s} - \frac{2}{s+1} + \frac{1}{s+2}$$

Increasing Laplace transformation gives,

$$y(t) = (1 - 2e^{-t} + e^{-2t})u(t)$$

MCQ 1.37Consider the following statements S1 and S2S1 : At the resonant frequency the impedance of a series RLC circuit is zero.S2 : In a parallel GLC circuit, increasing the conductance G results in increase in its Q factor.

Which one of the following is correct?

- (A) S1 is FALSE and S2 is TRUE
- (B) Both S1 and S2 are TRUE
- (C) S1 is TRUE and S2 is FALSE
- (D) Both S1 and S2 are FALSE
- **SOL 1.37** Impedance of series RLC circuit at resonant frequency is minimum, not zero. Actually imaginary part is zero.

$$Z = R + j \left(\omega L - \frac{1}{\omega C} \right)$$

At resonance $\omega L - \frac{1}{\omega C} = 0$ and Z = R that is purely resistive. Thus S_1 is false Now quality factor $Q = R \sqrt{\frac{C}{L}}$

Since
$$G = \frac{1}{R}$$
, $Q = \frac{1}{G}\sqrt{\frac{G}{R}}$

If $G \uparrow$ then $Q \downarrow$ provided C and L are constant. Thus S_2 is also false. Hence (D) is correct option.

In an abrupt p-n junction, the doping concentrations on the p-side and n-side **MCQ 1.38** are $N_A = 9 \times 10^{16}$ /cm³ respectively. The p - n junction is reverse biased and the total depletion width is 3 μ m. The depletion width on the p-side is (Λ) 0 7

(A) 2.7
$$\mu$$
m
(C) 2.25 μ m
(C) 2.25 μ m
(B) 0.3 μ m
(C) 0.75 μ m

We know that **SOL 1.38** TTZ AT TAZ AZ

or

$$W_p N_A = W_n N_D$$

 $W_p = rac{W_n imes N_D}{N_A} = rac{3 \, \mu imes 10^{16}}{9 imes 10^{16}} = 0.3 \, \mu \mathrm{m}$

Hence option (B) is correct.

MCQ 1.39 The resistivity of a uniformly doped n-type silicon sample is 0.5Ω - mc. If the electron mobility (μ_n) is 1250 cm²/V-sec and the charge of an electron is 1.6×10^{-19} Coulomb, the donor impurity concentration (N_D) in the sample is

(A)
$$2 \times 10^{16}$$
/cm³
(B) 1×10^{16} /cm³
(C) 2.5×10^{15} /cm³
(D) 5×10^{15} /cm³

SOL 1.39 Hence option (B) is correct.

or resistivity

Thus

Conductivity $\sigma = nqu_n$ $\rho = \frac{1}{\sigma} = \frac{1}{nq\mu_n}$ $n = \frac{1}{q\rho\mu_n} = \frac{1}{1.6 \times 10^{-19} \times 0.5 \times 1250} = 10^{16} / \text{cm}^3$

For *n* type semiconductor $n = N_D$

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MCQ 1.40 Consider an abrupt p - n junction. Let V_{bi} be the built-in potential of this junction and V_R be the applied reverse bias. If the junction capacitance (C_i) is 1 pF for $V_{bi} + V_R = 1$ V, then for $V_{bi} + V_R = 4$ V, C_j will be (A) 4 pF(B) 2 pF(C) 0.25 pF (D) 0.5 pF

SOL 1.40 We know that

$$C_{j} = \left[\frac{e\varepsilon_{S}N_{A}N_{D}}{2(V_{bi} + V_{R})(N_{A} + N_{D})}\right]^{\frac{1}{2}}$$

Thus $C_{j} \propto \sqrt{\frac{1}{(V_{bi} + V_{R})}}$
Now $\frac{C_{j2}}{C_{j1}} = \sqrt{\frac{(V_{bi} + V_{R})_{1}}{(V_{bi} + V_{R})_{2}}} = \sqrt{\frac{1}{4}} = \frac{1}{2}$
or $C_{j2} = \frac{C_{j1}}{2} = \frac{1}{2} = 0.5 \text{ pF}$

or

Now

Hence option (D) is correct.

- MCQ 1.41 Consider the following statements Sq and S2.
 - S1 : The threshold voltage (V_T) of MOS capacitor decreases with increase in gate oxide thickness.
 - S2: The threshold voltage (V_T) of a MOS capacitor decreases with increase in substrate doping concentration.
 - Which Marks of the following is correct?
 - (A) S1 is FALSE and S2 is TRUE
 - (B) Both S1 and S2 are TRUE
 - (C) Both S1 and S2 are FALSE
 - (D) S1 is TRUE and S2 is FALSE
- SOL 1.41 Increase in gate oxide thickness makes difficult to induce charges in channel. Thus V_T increases if we increase gate oxide thickness. Hence S_1 is false. Increase in substrate doping concentration require more gate voltage because initially induce charges will get combine in substrate. Thus V_T increases if we increase substrate doping concentration. Hence S_2 is false. Hence option (C) is correct.
- MCQ 1.42 The drain of an n-channel MOSFET is shorted to the gate so that $V_{GS} = V_{DS}$. The threshold voltage (V_T) of the MOSFET is 1 V. If the drain current (I_D) is 1 mA for $V_{GS} = 2$ V, then for $V_{GS} = 3$ V, I_D is (A) 2 mA(B) 3 mA

(D) 4 mA

(C) 9 mA

SOL 1.42 We know that $I_D = K(V_{GS} - V_T)^2$ $\frac{I_{DS}}{I_{DI}} = \frac{(V_{GS2} - V_T)^2}{(V_{GS1} - V_T)^2}$ Thus Substituting the values we have $\frac{I_{D2}}{I_{D1}} = \frac{(3-1)^2}{(2-1)^2} = 4$ $I_{D2} = 4I_{DI} = 4 \text{ mA}$ or Hence option (D) is correct. **MCQ 1.43** The longest wavelength that can be absorbed by silicon, which has the bandgap of 1.12 eV, is 1.1 μ m. If the longest wavelength that can be absorbed by another material is 0.87 μ m, then bandgap of this material is (A) 1.416 A/cm^2 (B) 0.886 eV (C) 0.854 eV (D) 0.706 eV Hence option (A) is correct. **SOL 1.43** $E_g \propto \frac{1}{\lambda}$ $\frac{E_{g2}}{E_{g1}} = \frac{\lambda_1}{\lambda_2} = \frac{1.10}{0.87}$ **d l C** Thus $E_{g2} = \frac{1.1}{0.87} \times 1.12 = 1.416$ eV2 or The neutral base width of a bipolar transistor, biased in the active region, is 0.5 μ MCQ 1.44 m. The maximum electron concentration and the diffusion constant in the base are 10^{14} /cm³ and $D_n = 25$ cm²/sec respectively. Assuming negligible recombination in the base, the collector current density is (the electron charge is 1.6×10^{-19} Coulomb) (A) 800 A/cm^2 (B) 8 A/cm^2

(C)
$$200 \text{ A/cm}^2$$
 (D) 2 A/cm^2

SOL 1.44 Concentration gradient

$$\frac{dn}{dx} = \frac{10^{14}}{0.5 \times 10^{-4}} = 2 \times 10^{18}$$

$$q = 1.6 \times 10^{-19} C$$

$$D_n = 25$$

$$\frac{dn}{dx} = \frac{10^{14}}{0.5 \times 10^{-4}}$$

$$J_C = q D_n \frac{dn}{dx}$$

$$= 1.6 \times 10^{-19} \times 25 \times 2 \times 10^{18} = 8 \text{ A/cm}^2$$

Hence option (B) is correct.

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Assume that the β of transistor is extremely large and $V_{BE} = 0.7 V, I_C$ and V_{CE} in **MCQ 1.45** the circuit shown in the figure



(A)
$$I_C = 1 \text{ mA}, V_{CE} = 4.7 \text{ V}$$

(C) $I_C = 1 \text{ mA}, V_{CE} = 2.5 \text{ V}$

(B) $I_C = 0.5 \text{ mA}, V_{CE} = 3.75 \text{ V}$ (D) $I_C = 0.5 \text{ mA}, V_{CE} = 3.9 \text{ V}$



The theorem equivalent is shown below



Since β is large is large, $I_C \approx I_E$, $I_B \approx 0$ and $I_E = \frac{V_T - V_{BE}}{R_E} = \frac{1 - 0.7}{300} = 3 \text{ mA}$

Now
$$V_{CE} = 5 - 2.2 \text{k} I_C - 300 I_E$$

= 5 - 2.2k × 1m - 300 × 1m
= 2.5 V

Hence (C) is correct option

MCQ 1.46 A bipolar transistor is operating in the active region with a collector current of 1 mA. Assuming that the β of the transistor is 100 and the thermal voltage (V_T) is 25 mV, the transconductance (g_m) and the input resistance (r_{π}) of the transistor in the common emitter configuration, are

- (A) $g_m = 25 \text{ mA/V}$ and $r_\pi = 15.625 \text{ k}\Omega$
- (B) $g_m = 40 \text{ mA/V}$ and $r_\pi = 4.0 \text{ k}\Omega$
- (C) $g_m = 25 \text{ mA/V}$ and $r_{\pi} = 2.5 \text{ k} \Omega$
- (D) $g_m = 40 \text{ mA/V}$ and $r_\pi = 2.5 \text{ k}\Omega$

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When $|I_C| >> |I_{CO}|$ $g_m = \frac{|I_C|}{V_T} = \frac{1\text{mA}}{25\text{mV}} = 0.04 = 40 \text{ mA/V}$ **SOL 1.46** $r_{\pi} = \frac{\beta}{g_m} = \frac{100}{40 \times 10^{-3}} = 2.5 \text{ k}\Omega$

Hence (D) is correct option.

MCQ 1.47 The value of C required for sinusoidal oscillations of frequency 1 kHz in the circuit of the figure is



SOL 1.47

The given circuit is wein bridge oscillator. The frequency of oscillation is $2\pi f = \frac{1}{RC}$

or

 $C = \frac{1}{2\pi Rf} = \frac{1}{2\pi \times 10^3 \times 10^3} = \frac{1}{2\pi}\mu$

Hence (A) is correct option.

MCQ 1.48

In the op-amp circuit given in the figure, the load current i_L is



(D) $\frac{V_s}{R_1}$

(C)
$$-\frac{V_s}{R_L}$$



The circuit is as shown below



We know that for ideal OPAMP $V_{-} = V_{+}$ Applying KCL at inverting terminal $\frac{V_{-}-V_{s}}{R_{1}} + \frac{V_{-}-V_{0}}{R_{1}} = 0$ $2V_{-}-V_{o}=V_{s}$...(1)or Applying KCL at non-inverting terminal $\frac{V_{+}}{R_{2}} + I_{L} + \frac{V_{+} - V_{0}}{R_{2}} = 0$ or $2V_+ - V_o + I_L R_2 = 0$ Since $V_- = V_+$, from (1) and (2) we have ...(2) $V_s + I_L R_2 = 0$ $I_L = -\frac{V_s}{R_2}$ or

Hence (A) is correct option.

MCQ 1.49 In the voltage regulator shown in the figure, the load current can vary from 100 mA to 500 mA. Assuming that the Zener diode is ideal (i.e., the Zener knee current is negligibly small and Zener resistance is zero in the breakdown region), the value of R is





If I_Z is negligible the load current is

	$\frac{12-V_z}{R} = I_L$	
	as per given condition	
	$100 \text{ mA} \le \frac{12 - V_Z}{R} \le 500 \text{ mA}$	
	At $I_L = 100 \text{ mA} \frac{12-5}{R} = 100 \text{ mA}$	$V_Z = 5 V$
	or $R = 70\Omega$	
	At $I_L = 500 \text{ mA} \frac{12-5}{R} = 500 \text{ mA}$	$V_Z = 5 V$
	or $R = 14 \Omega$	
	Thus taking minimum we get	
	$R = 14 \Omega$ Hence (D) is correct option	
MCQ 1.50	In a full-wave rectifier using two ideal di- of the voltage respectively across a resist of the diode, then the appropriate relati (A) $V_{de} = \frac{V_m}{m}$. $PIV = 2V_m$	ive load. If PIV is the peak inverse voltage onships for this rectifier are (B) $L_{te} = 2 \frac{V_m}{r}$. $PIV = 2 V_m$
	π ,	$(-)$ -uc - π , π
	(C) $V_{dc} = 2 \frac{V_m}{\pi}$, $PIV = V_m \mathbf{U}$	(D) $V_{dc} \frac{V_m}{\pi}$, $PIV = V_m$
SOL 1.50	Hence (B) is correct option.	el n
MCQ 1.51	The minimum number of 2- to -1 m multiplexers is	ultiplexers required to realize a 4- to -1
	(A) 1	(B) 2
	(C) 3	(D) 4
SOL 1.51	Number of MUX is $\frac{4}{3} = 2$ and $\frac{2}{2} = 1$. required. Hence (C) is correct answer.	Thus the total number 3 multiplexers is
MCQ 1.52	The Boolean expression $AC + B\overline{C}$ is eq	uivalent to
	(A) $\overline{A}C + B\overline{C} + AC$	(B) $\overline{B}C + AC + B\overline{C} + \overline{A}C\overline{B}$
	(C) $AC + B\overline{C} + \overline{B}C + ABC$	(D) $ABC + \overline{A}B\overline{C} + AB\overline{C} + A\overline{B}C$
SOL 1.52	Hence (D) is correct answer. $AC + B\overline{C} = AC1 + B\overline{C}1$ $= AC(B + \overline{B}) + B\overline{C}(A + BC)$ $= ACB + AC\overline{B} + B\overline{C}A + B\overline{C}A$	\overline{A}) $B\overline{CA}$
MCQ 1.53	11001, 1001, 111001 correspond to the 2 of the following sets of number	's complement representation of which one
	(A) 25,9, and 57 respectively	(B) -6, -6, and -6 respectively

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	(C) -7, -7 and -7 respe	ctively	(D) -25, -9 and	-57 respectively
SOL 1.53	Hence (C) is correct an	nswer.		
	11001	1001	111001	
	00110	0110	000110	
	+1	+1	+1	
	$\overline{00111}$	0111	$\overline{000111}$	
	7	7	7	
	Thus 2's complement of	of 11001, 1001	and 111001 is 7. So	the number given in the
	question are 2's comple	ement correspo	and to -7 .	
MCQ 1.54	The 8255 Programmab	le Peripheral	Interface is used as d	lescribed below.
	(i) An A/D converter is interface to a microprocessor through an 8255.			
	The conversion is initiated by a signal from the 8255 on Port C. A signal on Port			
	C causes data to be ste	obed into Port	; А.	
	(ii) Two computers e	xchange data	using a pair of 82	55s. Port A works as a
	bidirectional data port supported by appropriate handshaking signals.			
	The appropriate mode	s of operation	of the 8255 for (i) and	nd (ii) would be
	(A) Mode 0 for (i) and	Mode 1 for (i		
	(B) Mode 1 for (i) and	Mode 2 for (i	i) G	
	(C) Mode for (i) and Mode 0 for (ii)			
	(D) Mode 2 for (i) and	Mode 1 for (i	ii) CI L	
SOL 1.54	For 8255, various mode	es are describe	ed as following.	
	Mode 1 : Input or outp	put with hand	shake	
	In this mode following	actions are ex	recuted	
	1. Two port (A & B)	function as 8	- bit input output p	orts.
	2. Each port uses thr	ree lines from (C as a hand shake si	gnal
	3. Input & output da	ata are latched		
	Form (ii) the mode is 1	1.		
	Mode 2 : Bi-directional data transfer			
	TT1 · 1. · 1 / . /			T (1 · 1) (A

This mode is used to transfer data between two computer. In this mode port A can be configured as bidirectional port. Port A uses five signal from port C as hand shake signal.

For (1), mode is 2

Hence (D) is correct answer.

MCQ 1.55 The number of memory cycles required to execute the following 8085 instructions
 (i) LDA 3000 H
 (ii) LXI D, FOF1H
 would be

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	(A) 2 for (i) and 2 for (ii)(C) 3 for (i) and 3 for (ii)	(B) 4 for (i) and 3 for(D) 3 for (i) and 4 for	(ii) (ii)
SOL 1.55	 LDA 16 bit ⇒ Load accumula memory location (specified with It takes 4 memory cycle-as foll 1. in instruction fetch 2. in reading 16 bit address 	ator directly this instruction copi thin the instruction) the accumula owing.	ies data byte from ator.
	1. in copying data from mem LXI D, $(F0F1)_4 \Rightarrow$ It copies 16 It takes 3 memory cycles. Hence (B) is correct answer.	ory to accumulator 3 bit data into register pair D and	l E.
MCQ 1.56	In the modulo-6 ripple counter used to clear the J-K flip-flop The 2-input gate is $\frac{1}{C - J} = B - J = A$	shown in figure, the output of	he 2- input gate is



(\mathbf{A})	a NAND gate
(C)	an OR gate

(B) a NOR gate(D) a AND gare

SOL 1.56 In the modulo - 6 ripple counter at the end of sixth pulse (i.e. after 101 or at 110) all states must be cleared. Thus when CB is 11 the all states must be cleared. The input to 2-input gate is \overline{C} and \overline{B} and the desired output should be low since the CLEAR is active low Thus when \overline{C} and \overline{B} are 0, 0, then output must be 0. In all other case the output

must be 1. OR gate can implement this functions. Hence (C) is correct answer.

MCQ 1.57 Consider the sequence of 8085 instructions given below

LXI H, 9258 MOV A, M CMA MOV M, A Which one of the following is performed by this sequence ? (A) Contents of location 9258 are moved to the accumulator

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	(B) Contents of location 9258 are compared with the contents(C) Contents of location 8529 are complemented and stored i(D) Contents of location 5892 are complemented and stored i	s of the accumulator n location 8529 n location 5892
SOL 1.57	Hence (A) is correct answer. LXI H, 9258H ; 9258H \rightarrow HL MOV A, M ; (9258H) \rightarrow A CMa ; $\overline{A} \rightarrow A$ MOV M, A ; $A \rightarrow M$ This program complement the data of memory location 9258	Н.
MCQ 1.58	A Boolean function f of two variables x and y is defined as f f(0,0) = f(0,1) = f(1,1) = 1; f(1,0) = 0 Assuming complements of x and y are not available, a minim realizing f using only 2-input NOR gates and 2- input OR gates cost) would have a total cost of (A) 1 unit (C) 3 unit (D) 2 unit	follows : num cost solution for tes (each having unit
SOL 1.58	Hence (D) is correct answer. We have $f(x,y) = \overline{xy} + \overline{xy} + xy = \overline{x}(\overline{y} + y) + xy = \overline{x} + xy$ or $f(x,y) = \overline{x} + y$ Here compliments are not available, so to get \overline{x} we use NOP circuit require 1 unit OR and 1 unit NOR gate giving total co	y R gate. Thus desired ost 2 unit.
MCQ 1.59	It is desired to multiply the numbers 0AH by 0BH and sta accumulator. The numbers are available in registers B and C of the 8085 program for this purpose is given below : MVI A, 00H LOOP HLT END The sequence of instructions to complete the program would (A) JNX LOOP, ADD B, DCR C (B) ADD B, JNZ LOOP, DCR C (C) DCR C, JNZ LOOP, ADD B	ore the result in the c respectively. A part be
	(D) ADD B, DCR C, JNZ LOOP	
SOL 1.59	Hence (D) is correct answer. MVI A, 00H ; Clear accumulator LOOP ADD B ; Add the contents of B to A	
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	DCR C INZ LOOP	; Decrement C : If C is not zero jump to loop
	HLT END	
	This instruction set ad Hence (D) is correct as	d the contents of B to accumulator to contents of C times. nswer.
MCQ 1.60	A 1 kHz sinusoidal sign signal is passed throug output signal has the f (A) zero Hz	nal is ideally sampled at 1500 samples/sec and the sampled h an ideal low-pass filter with cut-off frequency 800 Hz . The frequency. (B) 0.75 kHz
	(C) 0.5 kHz	(D) 0.75 kHz (D) 0.25 kHz
SOL 1.60	Hence Correct Option Here $f_s = 1500$ s The sampled frequence 800 Hz, then only outp	is (C) samples/sec, $f_m = \text{kHz}$ cy are 2.5 kHz, 0.5 kHz, Since LPF has cut-off frequency out signal of frequency 0.5 kHz would pass through it
MCQ 1.61	A rectangular pulse traces $x(t)$ x(t) (0.1 msec)	ain $s(t)$ as shown in the figure is convolved with the signal onvolved signal will be a <u>gate</u> <u>hep</u> t
	(A) DC	(B) 12 kHz sinusoid
	(C) 8 kHz sinusoid	(D) 14 kHz sinusoid
SOL 1.61	Hence Correct Option S(t) =	is (D) = $\frac{1}{T_s} [1 + 2\cos\omega_s t + 2\cos2\omega_s t + \dots]$
	$\cos^2 4\pi \times 10^3 t =$	$=\frac{\left(1+\cos 8\pi\times 10^3t\right)}{2}$
	$\omega_s =$	$=\frac{2\pi}{0.1\times10^{-3}}=2\pi\times10\times10^{3}$
	S(t) * x(t) =	$=\int\limits_{-\infty}^{\infty}S(au) imes(au-t)d au$
	=	$= \int_{-\infty}^{\infty} 10 \times 10^3 [1 + 2\cos\omega_s t + 2\cos2\omega_s t + \dots] dt$
		$\times \frac{\left[1 + \cos 8\pi \times 10^3 t\right]}{2}$

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So, frequencies present will be $f_s \pm f_m, 2f_s \pm 3f_s \pm f_m; f_s = 10 \text{ kHz}$

$$f_m = rac{8\pi imes 10^3}{2\pi} = 4
m kHz$$

Hence 14 kHz sinusoidal signal will be present

- **MCQ 1.62** Consider the sequence x[n] = [-4 j51 + j25]. The conjugate anti-symmetric part of the sequence is
 - (A) [-4-j2.5, j2, 4-j2.5] (B) [-j2.5, 1, j2.5](C) [-j2.5, j2, 0] (D) [-4, 1, 4]

SOL 1.62 Hence (A) is correct answer. We have $x(n) = \begin{bmatrix} -4 - j5, & 1+2j, & 4 \end{bmatrix}$

$$x^{*}(n) = \begin{bmatrix} -4 + j5, & 1 - 2j, & 4 \end{bmatrix}$$

$$x^{*}(-n) = \begin{bmatrix} 4, & 1 - 2j, & -4 + j5 \end{bmatrix}$$

$$x_{cas}(n) = \frac{x(n) - x^{*}(-n)}{2}$$

$$= \begin{bmatrix} -4 - j\frac{5}{2}, & 2j & 4 - j\frac{5}{2} \end{bmatrix}$$

MCQ 1.63 A causal LTI system is described by the difference equation $2y[n] = \alpha y[n-2] - 2x[n] + \beta x[n-1]$

The system is stable only if

A) $ \alpha = 2, \beta < 2$	(B) $ \alpha > 2, \beta > 2$
C) $ \alpha < 2$, any value of β	(D) $ \beta < 2$, any value of α

SOL 1.63 Hence (C) is correct answer. We have $2y(n) = \alpha y(n-2) - 2x(n) + \beta x(n-1)$ Taking z transform we get $2Y(z) = \alpha Y(z) z^{-2} - 2X(z) + \beta X(z) z^{-1}$

or

or

$$\frac{Y(z)}{X(z)} = \left(\frac{\beta z^{-1} - 2}{2 - \alpha z^{-2}}\right)$$
$$H(z) = \frac{z(\frac{\beta}{2} - z)}{(z^2 - \frac{\alpha}{2})}$$

It has poles at $\pm \sqrt{\alpha/2}$ and zero at 0 and $\beta/2$. For a stable system poles must lie inside the unit circle of z plane. Thus

$$\left|\sqrt{\frac{\alpha}{2}}\right| < 1$$

$$|\alpha| < 2$$

But zero can lie anywhere in plane. Thus, β can be of any value.

...(i)

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A causal system having the transfer function H(s) = 1/(s+2) is excited with **MCQ 1.64** 10u(t). The time at which the output reaches 99% of its steady state value is (A) 2.7 sec(B) 2.5 sec(C) 2.3 sec(D) 2.1 sec **SOL 1.64** Hence (C) is correct option. We have r(t) = 10u(t) $R(s) = \frac{10}{s}$ or $H(s) = \frac{1}{s+2}$ Now $C(s) = H(s) \cdot R(s) = \frac{1}{s+2} \cdot \frac{10}{s} \frac{10}{s(s+2)}$ $C(s) = \frac{5}{s} - \frac{5}{s+2}$ or $c(t) = 5[1 - e^{-2t}]$ The steady state value of c(t) is 5. It will reach 99% of steady state value reaches at t, where $5[1 - e^{-2t}] = 0.99 \times 5$

or
$$1 - e^{-2t} = 0.99$$

 $e^{-2t} = 0.1$
or $-2t = \ln 0.1$
or $t = 2.3 \sec$ **Jate**

MCQ 1.65 The impulse response h[n] of a linear time invariant system is given as

$$h[n] = \begin{cases} -2\sqrt{2} & n = 1, -1\\ 4\sqrt{2} & n = 2, -2\\ 0 & \text{otherwise} \end{cases}$$

If the input to the above system is the sequence $e^{j\pi n/4}$, then the output is (A) $4\sqrt{2} e^{j\pi n/4}$ (B) $4\sqrt{2} e^{-j\pi n/4}$ (C) $4e^{j\pi n/4}$ (D) $-4e^{j\pi n/4}$

SOL 1.65 Hence (D) is correct answer. We have $x(n) = e^{j\pi n/4}$

have $x(n) = e^{j\pi n/4}$ $h(n) = 4\sqrt{2}\,\delta(n+2) - 2\sqrt{2}\,\delta(n+1) - 2\sqrt{2}\,\delta(n-1)$

 $+4\sqrt{2}\delta(n-2)$

Now

and

$$y(n) = x(n)^* h(n)$$

= $\sum_{k=-\infty}^{\infty} x(n-k)h(k) = \sum_{k=-2}^{2} x(n-k)h(k)$
 $y(n) = x(n+2)h(-2) + x(n+1)h(-1)$
+ $x(n-1)h(1) + x(n-2)h(2)$
= $4\sqrt{2} e^{j\frac{\pi}{4}(n+2)} - 2\sqrt{2} e^{j\frac{\pi}{4}(n+1)} - 2\sqrt{2} e^{j\frac{\pi}{4}(n-1)} + 4\sqrt{2} e^{j\frac{\pi}{4}(n-2)}$

or

or

$$\begin{split} &= 4\sqrt{2} \big[e^{j\frac{\pi}{4}(n+2)} + e^{j\frac{\pi}{4}(n-2)} \big] - 2\sqrt{2} \big[e^{j\frac{\pi}{4}(n+1)} + e^{j\frac{\pi}{4}(n-1)} \big] \\ &= 4\sqrt{2} \, e^{j\frac{\pi}{4}n} \big[e^{j\frac{\pi}{2}} + e^{-j\frac{\pi}{2}} \big] - 2\sqrt{2} \, e^{j\frac{\pi}{2}n} \big[e^{j\frac{\pi}{4}} + e^{-j\frac{\pi}{4}} \big] \\ &= 4\sqrt{2} \, e^{j\frac{\pi}{4}n} \big[0 \big] - 2\sqrt{2} \, e^{j\frac{\pi}{4}n} \big[2\cos\frac{\pi}{4} \big] \\ y(n) = -4e^{j\frac{\pi}{4}n} \end{split}$$

MCQ 1.66 Let x(t) and y(t) with Fourier transforms F(f) and Y(f) respectively be related as shown in Fig. Then Y(f) is



(C)
$$90^{\circ}$$
 (D) -180°

SOL 1.67 Approximate (comparable to 90°) phase shift are Due to pole at $0.01 \text{ Hz} \rightarrow -90^{\circ}$ Due to pole at $80 \text{ Hz} \rightarrow -90^{\circ}$ Due to pole at $80 \text{ Hz} \rightarrow 0$ Due to zero at $5 \text{ Hz} \rightarrow 90^{\circ}$ Due to zero at 100 Hz $\rightarrow 0$ Due to zero at 200 Hz $\rightarrow 0$ Thus approximate total -90° phase shift is provided. Hence (A) is correct option.

Consider the signal flow graph shown in Fig. The gain $\frac{x_5}{x_5}$ is **MCQ 1.68**

(A)
$$\frac{1 - (be + cf + dg)}{abcd}$$
(B)
$$\frac{bedg}{1 - (be + cf + dg)}$$
(C)
$$\frac{abcd}{1 - (be + cf + dg) + bedg}$$
(D)
$$\frac{1 - (be + cf + dg) + bedg}{abcd}$$
Mason Gain Formula
$$T(s) = \frac{\sum p_k \Delta_k}{\Delta}$$
In given SFG there is only one forward path and 3 possible loop.
$$p_1 = abcd$$

$$\Delta_1 = 1$$

 $\Delta = 1 - (\text{sum of individual loops}) - (\text{Sum of two non touching loops})$ $= 1 - (L_1 + L_2 + L_3) + (L_1 L_3)$ Non touching loop are L_1 and L_3 where

 $L_1L_2 = bedg$

Thus
$$\frac{C(s)}{R(s)} = \frac{p_1 \Delta_1}{1 - (be + cf + dg) + bedg}$$
$$= \frac{abcd}{1 - (be + cf + dg) + bedg}$$

Hence (C) is correct option

$$\begin{array}{ll} \textbf{MCQ 1.69} & \text{If } A = \begin{bmatrix} -2 & 2\\ 1 & -3 \end{bmatrix}, \text{ then } \sin At \text{ is} \\ & (A) \; \frac{1}{3} \begin{bmatrix} \sin \left(-4t \right) + 2\sin \left(-t \right) \; -2\sin \left(-4t \right) + 2\sin \left(-t \right) \\ -\sin \left(-4t \right) + \sin \left(-t \right) \; \; 2\sin \left(-4t \right) + \sin \left(-t \right) \end{bmatrix} \\ & (B) \; \begin{bmatrix} \sin \left(-2t \right) \; \sin \left(2t \right) \\ \sin \left(t \right) \; \sin \left(-3t \right) \end{bmatrix} \\ & (C) \; \frac{1}{3} \begin{bmatrix} \sin \left(4t \right) + 2\sin \left(t \right) \; \; 2\sin \left(-4t \right) - 2\sin \left(-t \right) \\ -\sin \left(-4t \right) + \sin \left(t \right) \; \; 2\sin \left(4t \right) + \sin \left(t \right) \end{bmatrix} \\ & (D) \; \frac{1}{3} \begin{bmatrix} \cos \left(-t \right) + 2\cos \left(t \right) \; \; 2\cos \left(-4t \right) + 2\cos \left(-t \right) \\ -\cos \left(-4t \right) + \cos \left(-t \right) \; \; -2\cos \left(-4t \right) + \cos \left(t \right) \end{bmatrix} \end{array}$$

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SOL 1.68

SOL 1.69 Hence (A) is correct option
We have
$$A = \begin{bmatrix} -2 & 2 \\ 1 & -3 \end{bmatrix}$$

Characteristic equation is
 $[\lambda I - A] = 0$
or $\begin{vmatrix} \lambda + 2 & -2 \\ -1 & \lambda + 3 \end{vmatrix} = 0$
or $(\lambda + 2)(\lambda + 3) - 2 = 0$
or $\lambda^2 + 5\lambda + 4 = 0$
Thus $\lambda_1 = -4$ and $\lambda_2 = -1$
Eigen values are -4 and -1 .
Eigen values are -4 and -1 .
Eigen vectors for $\lambda_1 = -4$
 $(\lambda_1 I - A) X_1 = 0$
or $\begin{bmatrix} \lambda_1 + 2 & -2 \\ 1 & \lambda_1 + 3 \end{bmatrix} \begin{bmatrix} x_{11} \\ x_{21} \end{bmatrix} = 0$
or $\begin{bmatrix} -2 & -2 \\ -1 & -1 \end{bmatrix} \begin{bmatrix} x_{11} \\ x_{21} \end{bmatrix} = 0$
or $-2x_{11} - 2x_{21} = 0$
We have only one independent equation $x_{11} = -x_{21}$.
Let $x_{21} = K$, then $x_{11} = -K$, the Eigen vector will be

$$\begin{bmatrix} x_{11} \\ x_{21} \end{bmatrix} = \begin{bmatrix} -K \\ K \end{bmatrix} = K \begin{bmatrix} -1 \\ 1 \end{bmatrix}$$

Now Eigen vector for $\lambda_2 = -1$ $(\lambda_2 I - A) X_2 = 0$

or
$$\begin{bmatrix} \lambda_2 + 2 & -2 \\ -1 & \lambda_2 + 3 \end{bmatrix} \begin{bmatrix} x_{12} \\ x_{22} \end{bmatrix} = 0$$

or
$$\begin{bmatrix} 1 & -2 \\ -1 & 2 \end{bmatrix} \begin{bmatrix} x_{12} \\ x_{22} \end{bmatrix} = 0$$

We have only one independent equation $x_{12} = 2x_{22}$ Let $x_{22} = K$, then $x_{12} = 2K$. Thus Eigen vector will be

$$\begin{bmatrix} x_{12} \\ x_{22} \end{bmatrix} = \begin{bmatrix} 2K \\ K \end{bmatrix} = K \begin{bmatrix} 2 \\ 1 \end{bmatrix}$$

Digonalizing matrix

$$M = \begin{bmatrix} x_{11} & x_{12} \\ x_{21} & x_{22} \end{bmatrix} = \begin{bmatrix} -1 & 2 \\ 1 & 1 \end{bmatrix}$$

Now
$$M^{-1} = \left(\frac{-1}{3}\right) \begin{bmatrix} 1 & -2 \\ -1 & -1 \end{bmatrix}$$

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Now Diagonal matrix of $\sin At$ is D where $D = \begin{bmatrix} \sin(\lambda_1 t) & 0 \\ 0 & \sin(\lambda_2 t) \end{bmatrix} = \begin{bmatrix} \sin(-4t) & 0 \\ 0 & \sin(\lambda_2 t) \end{bmatrix}$ Now matrix $B = \sin At = MDM^{-1}$

$$= -\left(\frac{1}{3}\right) \begin{bmatrix} -1 & 2\\ 1 & 1 \end{bmatrix} \begin{bmatrix} \sin\left(-4t\right) & 0\\ 0 & \sin\left(-t\right) \end{bmatrix} \begin{bmatrix} 1 & -2\\ -1 & -1 \end{bmatrix}$$
$$= -\left(\frac{1}{3}\right) \begin{bmatrix} -\sin\left(-4t\right) - 2\sin\left(-t\right) & 2\sin\left(-4t\right) - 2\sin\left(-t\right)\\ \sin\left(-4t\right) + 2\sin\left(t\right) & -2\sin\left(-4t\right) - 2\sin\left(-t\right) \end{bmatrix}$$
$$= -\left(\frac{1}{3}\right) \begin{bmatrix} -\sin\left(-4t\right) - 2\sin\left(-t\right) & 2\sin\left(-4t\right) - 2\sin\left(-t\right)\\ \sin\left(-4t\right) - \sin\left(-t\right) & -2\sin\left(-4t\right) + 2\sin\left(-t\right) \end{bmatrix}$$
$$= \left(\frac{1}{3}\right) \begin{bmatrix} \sin\left(-4t\right) + 2\sin\left(-t\right) & -2\sin\left(-4t\right) + 2\sin\left(-t\right)\\ -\sin\left(-4t\right) + 2\sin\left(-t\right) & 2\sin\left(-4t\right) + 2\sin\left(-t\right) \end{bmatrix} s$$

MCQ 1.70 The open-loop transfer function of a unity feedback system is

$$G(s) = \frac{K}{s(s^2 + s + 2)(s + 3)}$$

The range of K for which the system is stable is

(A)
$$\frac{21}{4} > K > 0$$
Y a i G (B) $13 > K > 0$

 (C) $\frac{21}{4} < K < \infty$
Figure 10 i G (D) $-6 < K < \infty$

SOL 1.70

1.70 For ufb system the characteristic equation is
$$1 + G(s) = 0$$

$$1 + \frac{K^{1+G(s)}}{s(s^2 + 2s + 2)(s+3)} = 0$$

$$s^4 + 4s^3 + 5s^2 + 6s + K = 0$$

The routh table is shown below. For system to be stable,

$$0 < K$$
 and $0 < \frac{(21 - 4K)}{2/7}$

This gives 0 $< K < \frac{21}{4}$

s^4	1	5	K	
s^3	4	6	0	
s^2	$\frac{7}{2}$	K		
s^1	$\frac{21-4K}{7/2}$	0		
s^0	K			

Hence (A) is correct option

For the polynomial $P(s) = s^2 + s^4 + 2s^3 + 2s^2 + 3s + 15$ the number of roots which **MCQ 1.71** lie in the right half of the s-plane is

- (A) 4(B) 2(C) 3 (D) 1
- Hence (B) is correct option. SOL 1.71 We have $P(s) = s^5 + s^4 + 2s^3 + 3s + 15$ The routh table is shown below.

If $\varepsilon \to 0^+$ then $\frac{2\varepsilon+12}{\varepsilon}$ is positive and $\frac{-15\varepsilon^2-24\varepsilon-144}{2\varepsilon+12}$ is negative. Thus there are two sign change in first column. Hence system has 2 root on RHS of plane.

s^5	1	2	3		
s^4	1	2	15		
s^3	ε	-12	0		
s^2	$\frac{2\varepsilon + 12}{\varepsilon}$	15	0		
s^1	$\frac{-15\varepsilon^2 - 24\varepsilon - 144}{2\varepsilon + 12}$				
s^0	0				
Y C L L					

- The state variable equations of a system are : $\dot{x_1} = -3x_1 x_2 = u, \dot{x_2} = 2x_1$ and **MCQ 1.72** $y = x_1 + u$. The system is
 - (A) controllable but not observable
 - (B) observable but not controllable
 - (C) neither controllable nor observable
 - (D) controllable and observable

SOL 1.72

Hence (D) is correct option. We have $\begin{bmatrix} x_1 \\ x_2 \end{bmatrix} = \begin{bmatrix} -3 & -1 \\ 2 & 0 \end{bmatrix} \begin{bmatrix} x_1 \\ x_2 \end{bmatrix} + \begin{bmatrix} 1 \\ 0 \end{bmatrix} u$ $Y = \begin{bmatrix} 1 & 0 \end{bmatrix} \begin{bmatrix} x_1 \\ x_2 \end{bmatrix} + \begin{bmatrix} 1 \\ 2 \end{bmatrix} u$ and $A = \begin{bmatrix} -3 & -1 \\ 2 & 0 \end{bmatrix}, B = \begin{bmatrix} 1 \\ 0 \end{bmatrix} \text{ and } C = \begin{bmatrix} 1 & 0 \end{bmatrix}$ Here The controllability matrix is $Q_C = [B \ AB]$

$$= \begin{bmatrix} 1 & -3 \\ 0 & 2 \end{bmatrix}$$

det $Q_C \neq 0$ The observability matrix is Thus controllable

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MCQ 1.74 Consider the signal x(t) shown in Fig. Let h(t) denote the impulse response of the filter matched to x(t), with h(t) being non-zero only in the interval 0 to 4 sec. The slope of h(t) in the interval 3 < t < 4 sec is



$$h(t) = x(4-t)$$

The graph of h(t) is as shown below.

SOL 1.74



From graph it may be easily seen that slope between 3 < t < 4 is -1. Hence (B) is correct option.

MCQ 1.75 A 1 mW video signal having a bandwidth of 100 MHz is transmitted to a receiver through cable that has 40 dB loss. If the effective one-side noise spectral density at the receiver is 10⁻²⁰ Watt/Hz, then the signal-to-noise ratio at the receiver is

(B) 30 dB

(C) 40 dB
(D) 60 dB
SOL 1.75 The SNR at transmitter is

$$SNR_{tr} = \frac{P_{tr}}{\mathbb{N}B}$$

 $\frac{10^{-3}}{10^{-20} \times 100 \times 10^6} = 10^9$
In dB $SNR_{tr} = 10 \log 10^9$
Cable Loss = 40 db
At receiver after cable loss we have
 $SNR_{Rc} = 90 - 40 = 50$ dB
Hence (A) is correct option.

(A) 50 dB

MCQ 1.76 A 100 MHz carrier of 1 V amplitude and a 1 MHz modulating signal of 1 V amplitude are fed to a balanced modulator. The ourput of the modulator is passed through an ideal high-pass filter with cut-off frequency of 100 MHz. The output of the filter is added with 100 MHz signal of 1 V amplitude and 90° phase shift as shown in the figure. The envelope of the resultant signal is



The output of balanced modulator is

$$V_{BM}(t) = [\cos \omega_c t] [\cos \omega_c t]$$

= $\frac{1}{2} [\cos (\omega_c + \omega_m) t + \cos (\omega_c - \omega_m) t]$

 $V_0(t) = V_{HP}(t) + \sin(2\pi \times 100 \times 10^6) t$

If $V_{BM}(t)$ is passed through HPF of cut off frequency $f_H = 100 \times 10^6$, then only $(\omega_c + \omega_m)$ passes and output of HPF is

$$V_{HP}(t) = rac{1}{2} \cos\left(\omega_c + \omega_m
ight) t$$

Now

$$= \frac{1}{2} \cos \left[2\pi 100 \times 10^6 + 2\pi \times 1 \times 10^6 t \right] + \sin \left(2\pi \times 100 \times 10^6 \right) t$$

$$= \frac{1}{2} \cos \left[2\pi 10^8 + 2\pi 10^6 t \right] + \sin \left(2\pi 10^8 \right) t$$

$$= \frac{1}{2} \left[\cos \left(2\pi 10^8 t \right) t \cos \left(2\pi 10^6 t \right) \right] - \sin \left[2\pi 10^8 t \sin \left(2\pi 10^6 t \right) + \sin 2\pi 10^8 t \right]$$

$$= \frac{1}{2} \cos \left(2\pi 10^6 t \right) \cos 2\pi 10^8 t + \left(1 - \frac{1}{2} \sin 2\pi 10^6 t \right) \sin 2\pi 10^8 t$$

in form

This signal is in form

The envelope of this signal is

$$= A \cos 2\pi 10^8 t + B \sin 2\pi 10^8 t$$
The envelope of this signal is

$$= \sqrt{A^2 + B^2}$$

$$= \sqrt{\left(\frac{1}{2}\cos\left(2\pi 10^6 t\right)\right)^2 + \left(1 - \frac{1}{2}\sin\left(2\pi 10^6 t\right)\right)^2}$$

$$= \sqrt{\frac{1}{4}\cos^2(2\pi 10^6 t) + 1 + \frac{1}{4}\sin^2(2\pi 10^6 t) - \sin\left(2\pi 10^6 t\right)}$$

$$= \sqrt{\frac{1}{4} + 1 - \sin\left(2\pi 10^6 t\right)}$$

$$= \sqrt{\frac{5}{4} - \sin\left(2\pi 10^6 t\right)}$$

MCQ 1.77 Two sinusoidal signals of same amplitude and frequencies 10 kHz and 10.1 kHz are added together. The combined signal is given to an ideal frequency detector. The output of the detector is

SOL 1.77 Hence (A) is correct option.

$$s(t) = A\cos[2\pi 10 \times 10^{3} t] + A\cos[2\pi 10.1 \times 10^{3} t]$$
$$T_{1} = \frac{1}{10 \times 10^{3}} = 100\mu \sec$$

Here

and

$$T_2 = \frac{1}{10.1 \times 10^3} = 99\mu \sec \theta$$

Period of added signal will be LCM $[T_1, T_2]$

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Thus
$$T = LCM[100,99] = 9900\mu \sec$$

Thus frequency $f = \frac{1}{9900\mu} = 0.1 \text{ kHz}$

MCQ 1.78 Consider a binary digital communication system with equally likely 0's and 1's. When binary 0 is transmitted the detector input can lie between the levels -0.25 V and +0.25 V with equal probability : when binary 1 is transmitted, the voltage at the detector can have any value between 0 and 1 V with equal probability. If the detector has a threshold of 0.2 V (i.e., if the received signal is greater than 0.2 V, the bit is taken as 1), the average bit error probability is (A) 0.15 (B) 0.2

$$(C) 0.05 (D) 0.5 (D) 0.5$$

SOL 1.78

1.78 The pdf of transmission of 0 and 1 will be as shown below :



Hence (A) is correct option.

- **MCQ 1.79** A random variable X with uniform density in the interval 0 to 1 is quantized as follows :
 - If $0 \le X \le 0.3$, $x_q = 0$ If $0.3 < X \le 1$, $x_q = 0.7$ where x_q is the quantized value of X.The root-mean square value of the quantization noise is(A) 0.573(B) 0.198(C) 2.205(D) 0.266
- **SOL 1.79** Hence (B) is correct option. The square mean value is

$$\sigma^2 = \int_{-\infty}^{\infty} (x - x_q)^2 f(x) \, dx$$

MCQ

SOL

Q

$$= \int_{0}^{1} (x - x_{0})^{2} f(x) dx$$

$$= \int_{0}^{0.3} (x - 0)^{2} f(x) dx + \int_{0.3}^{0.1} (x - 0.7)^{2} f(x) dx$$

$$= \left[\frac{x^{3}}{3}\right]_{0}^{0.3} + \left[\frac{x^{3}}{3} + 0.49x - 14\frac{x^{2}}{2}\right]_{0.3}^{1}$$
or
$$\sigma^{2} = 0.039$$
RMS = $\sqrt{\sigma^{2}} = \sqrt{0.039} = 0.198$
1.80 Choose the current one from among the alternative *A*, *B*, *C*, *D* after matching an item from Group 1 with the most appropriate item in Group 2.
Group 1 Group 2
1. FM P. Slope overload
2. DM Q. μ -law
3. PSK R. Envelope detector
4. PCM
5. Hilbert transform
7. Hilbert tran

MCQ 1.81 Three analog signals, having bandwidths 1200 Hz, 600 Hz and 600 Hz, are sampled at their respective Nyquist rates, encoded with 12 bit words, and time division multiplexed. The bit rate for the multiplexed. The bit rate for the multiplexed signal is (\mathbf{D}) $\mathbf{a} \mathbf{a} \mathbf{a} \mathbf{b}$ $\mathbf{1}$

(A) 115.2 kbps	(B) 28.8 kbps
(C) 57.6 kbps	(D) 38.4 kbps

SOL 1.81 Since $f_s = 2f_m$, the signal frequency and sampling frequency are as follows

 $f_{m1} = 1200 \text{ Hz} \longrightarrow 2400 \text{ samples per sec}$

 $f_{m2} = 600 \text{ Hz} \longrightarrow 1200 \text{ samples per sec}$

 $f_{m3} = 600 \text{ Hz} \longrightarrow 1200 \text{ samples per sec}$

Thus by time division multiplexing total 4800 samples per second will be sent. Since each sample require 12 bit, total 4800×12 bits per second will be sent Thus bit rate $R_b = 4800 \times 12 = 57.6$ kbps Hence (C) is correct option.

Consider a system shown in the figure. Let X(f) and Y(f) and denote the Fourier **MCQ 1.82**

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transforms of x(t) and y(t) respectively. The ideal HPF has the cutoff frequency 10 kHz.



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MCQ 1.84 A source produces binary data at the rate of 10 kbps. The binary symbols are represented as shown in the figure given below.



The source output is transmitted using two modulation schemes, namely Binary PSK (BPSK) and Quadrature PSK (QPSK). Let B_1 and B_2 be the bandwidth requirements of BPSK and QPSK respectively. Assume that the bandwidth of he above rectangular pulses is 10 kHz, B_1 and B_2 are

(A)
$$B_1 = 20 \text{ kHz}, B_2 = 20 \text{ kHz}$$

(B) $B_1 = 10 \text{ kHz}, B_2 = 20 \text{ kHz}$
(C) $B_1 = 20 \text{ kHz}, B_2 = 10 \text{ kHz}$
(D) $B_1 = 20 \text{ kHz}, B_2 = 10 \text{ kHz}$

SOL 1.84 The required bandwidth of *M* array PSK is

$$BW = \frac{2R_b}{n}$$

where $2^n = M$ and R_b is bit rate For BPSK, $M = 2 = 2^n \longrightarrow n = 1$

Thus

$$B_1 = \frac{2R_b}{1} = 2 \times 10 = 20 \text{ kHz}$$
$$M = 4 = 2^n \longrightarrow n = 2$$

For QPSK,

Thus

$$B_2 = \frac{2R_b}{2} = 10 \text{ kHz}$$

Hence (C) is correct option.

MCQ 1.85 Consider a 300 Ω , quarter - wave long (at 1 GHz) transmission line as shown in Fig. It is connected to a 10 V, 50 Ω source at one end and is left open circuited at the other end. The magnitude of the voltage at the open circuit end of the line is



1

or
$$V_L = \frac{Z_0}{Z_{in}} V_{in} = \frac{10 \times 300}{50} = 60 \text{ V}$$

MCQ 1.86 In a microwave test bench, why is the microwave signal amplitude modulated at 1 kHz
(A) To increase the sensitivity of measurement
(B) To transmit the signal to a far-off place
(C) To study amplitude modulations
(D) Because crystal detector fails at microwave frequencies
SOL 1.86 Hence (D) is correct option.
MCQ 1.87 If $\vec{E} = (\hat{a}_x + j\hat{a}_y) e^{jkz \cdot k\omega t}$ and $\vec{H} = (k/\omega\mu) (\hat{a}_y + k\hat{a}_x) e^{jkz \cdot j\omega t}$, the time-averaged Poynting
vector is
(A) null vector
(B) $(k/\omega\mu) \hat{a}_z$
SOL 1.87 Hence (A) is correct option.
 $R_{avy} = \frac{1}{2} \operatorname{Re}[\vec{E} \times \vec{H}]$
 $\vec{E} \times \vec{H} = (\hat{a}_x + j\hat{a}_y) e^{jkz \cdot \vec{E} \cdot \vec{L}} \frac{k}{\omega\mu} (-j\hat{a}_x + \hat{a}_y) e^{-jkz + j\omega t}$
 $= \hat{a}_z [\frac{k}{\omega\mu} - (-j) (j) \frac{k}{\omega\mu}]$
Thus $R_{avg} = \frac{1}{2} \operatorname{Re}[\vec{E} \times \vec{H}] = 0$

Consider an impedance Z = R + jX marked with point P in an impedance Smith **MCQ 1.88** chart as shown in Fig. The movement from point P along a constant resistance circle in the clockwise direction by an angle 45° is equivalent to



(A) adding an inductance in series with Z

- (B) adding a capacitance in series with Z
- (C) adding an inductance in shunt across Z
- (D) adding a capacitance in shunt across Z

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Suppose at point P impedance is **SOL 1.88**

$$Z = r + j(-1)$$

5i

If we move in constant resistance circle from point P in clockwise direction by an angle 45°, the reactance magnitude increase. Let us consider a point Q at 45° from point P in clockwise direction. It's impedance is

$$Z_1 = r - 0.$$

$$Z_1 = Z + 0.5j$$

Thus movement on constant r - circle by an $\angle 45^{\circ}$ in CW direction is the addition of inductance in series with Z.

Hence (A) is correct option.

MCQ 1.89 A plane electromagnetic wave propagating in free space is incident normally on a large slab of loss-less, non-magnetic, dielectric material with $\varepsilon > \varepsilon_0$. Maxima and minima are observed when the electric field is measured in front of the slab. The maximum electric field is found to be 5 times the minimum field. The intrinsic impedance of the medium should be

	(A) $120\pi \Omega$ (C) $600\pi \Omega$	(B) $60\pi \Omega$ (D) $24\pi \Omega$		
SOL 1.89	Hence (D) is correct option.			
	We have	$\text{VSWR} = \frac{E_{\text{max}}}{E_{\text{min}}} = 5 = \frac{1 + \Gamma }{1 + \Gamma }$		
	or	$ \Gamma = \frac{2}{3}$ IEIP		
	Thus	$\Gamma = -\frac{2}{3}$		
	Now	$\Gamma=rac{\eta_2-\eta_1}{\eta_2+\eta_1}$		
	or	$-rac{2}{3}=rac{\eta_2-120\pi}{\eta_2+120\pi}$		
	or	$\eta_2 = 24\pi$		
MCQ 1.90	A lossless t	ransmission line is terminated in a loa		

ad which reflects a part of the Μ incident power. The measured VSWR is 2. The percentage of the power that is reflected back is

(A) 57.73	(B) 33.33
(C) 0.11	(D) 11.11

SOL 1.90 Hence (D) is correct option. $2 = \frac{1 - |\Gamma|}{1 + |\Gamma|}$ The VSWR $|\Gamma| = \frac{1}{3}$

Thus

$$\frac{P_{ref}}{P_{inc}} = |\Gamma|^2 = \frac{1}{9}$$
$$P_{ref} = \frac{P_{inc}}{9}$$

or

i.e. 11.11% of incident power is reflected.

Answer Sheet									
1.	(B)	19.	(A)	37.	(D)	55.	(B)	73.	(B)
2.	(D)	20.	(D)	38.	(B)	56.	(C)	74.	(B)
3.	(A)	21.	(D)	39.	(B)	57.	(A)	75.	(A)
4.	(A)	22.	(C)	40.	(D)	58.	(D)	76.	(C)
5.	(C)	23.	(D)	41.	(C)	59.	(D)	77.	(A)
6.	(C)	24.	(C)	42.	(D)	60.	(C)	78.	(A)
7.	(A)	25.	(C)	43.	(A)	61.	(D)	79.	(B)
8.	(D)	26.	(B)	44.	(B)	62.	(A)	80.	(C)
9.	(B)	27.	(B)	45.	(C)	63.	(C)	81.	(C)
10.	(C)	28.	(A)	46.	(D)	64.	(C)	82.	(B)
11.	(A)	29.	(D)	47.	(A)	65.	(D)	83.	(D)
12.	(A)	30.	(A)	48.	(A)	66.	(B)	84.	(C)
13.	(C)	31.	(D)	49.	(D)	67.	(A)	85.	(C)
14.	(A)	32.	(B)	50.	(B)	68.	(C)	86.	(D)
15.	(D)	33.	(C)	51.	(C)	69.	(A)	87.	(A)
16.	(B)	34.	(B)	52.	(D)	70	(A)	88.	(A)
17.	(A)	35.	(D)	53.	(C)	71	(B)	89.	(D)
18.	(C)	36.	(A)	54.	(D)	72	(D)	90.	(D)

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